UNITED STATES
SECURITIES AND EXCHANGE COMMISSION
Washington, D.C. 20549

FORM 8-K

CURRENT REPORT
Pursuant to Section 13 or 15(d)
of The Securities Exchange Act of 1934

June 21, 2016
Date of Report (Date of earliest event reported)

DIODES INCORPORATED
(Exact name of registrant as specified in its charter)

Delaware	**002-25577**	**95-2039518**
(State or other jurisdiction of incorporation)	**(Commission File Number)**	**(IRS Employer Identification No.)**

4949 Hedgcoxe Road, Suite 200 **Plano, Texas** **(Address of principal executive offices)**	**75024** **(Zip Code)**

(972) 987-3900
(Registrant's telephone number, including area code)

Check the appropriate box below if the Form 8-K filing is intended to simultaneously satisfy the filing obligation of the registrant under any of the following provisions:

☐ Written communications pursuant to Rule 425 under the Securities Act (17 CFR 230.425)

☐ Soliciting material pursuant to Rule 14a-12 under the Exchange Act (17 CFR 240.14a-12)

☐ Pre-commencement communications pursuant to Rule 14d-2(b) under the Exchange Act (17 CFR 240.14d-2(b))

☐ Pre-commencement communications pursuant to Rule 13e-4(c) under the Exchange Act (17 CFR 240.13e-4(c))

Item 8.01 Other Events.

From time to time, Diodes Incorporated (the "Company") may give corporate presentations to its customers, suppliers and other related interested parties. A copy of the Company's corporate presentation slides, updated on June 21, 2016, is attached herewith as Exhibit 99.1.

Item 9.01 Financial Statements and Exhibits.

(d) Exhibits.

Exhibit Number	Description
99.1	Corporate Presentation Slides

SIGNATURES

Pursuant to the requirements of the Securities Exchange Act of 1934, the Registrant has duly caused this report to be signed on its behalf by the undersigned hereunto duly authorized.

Dated: June 21, 2016

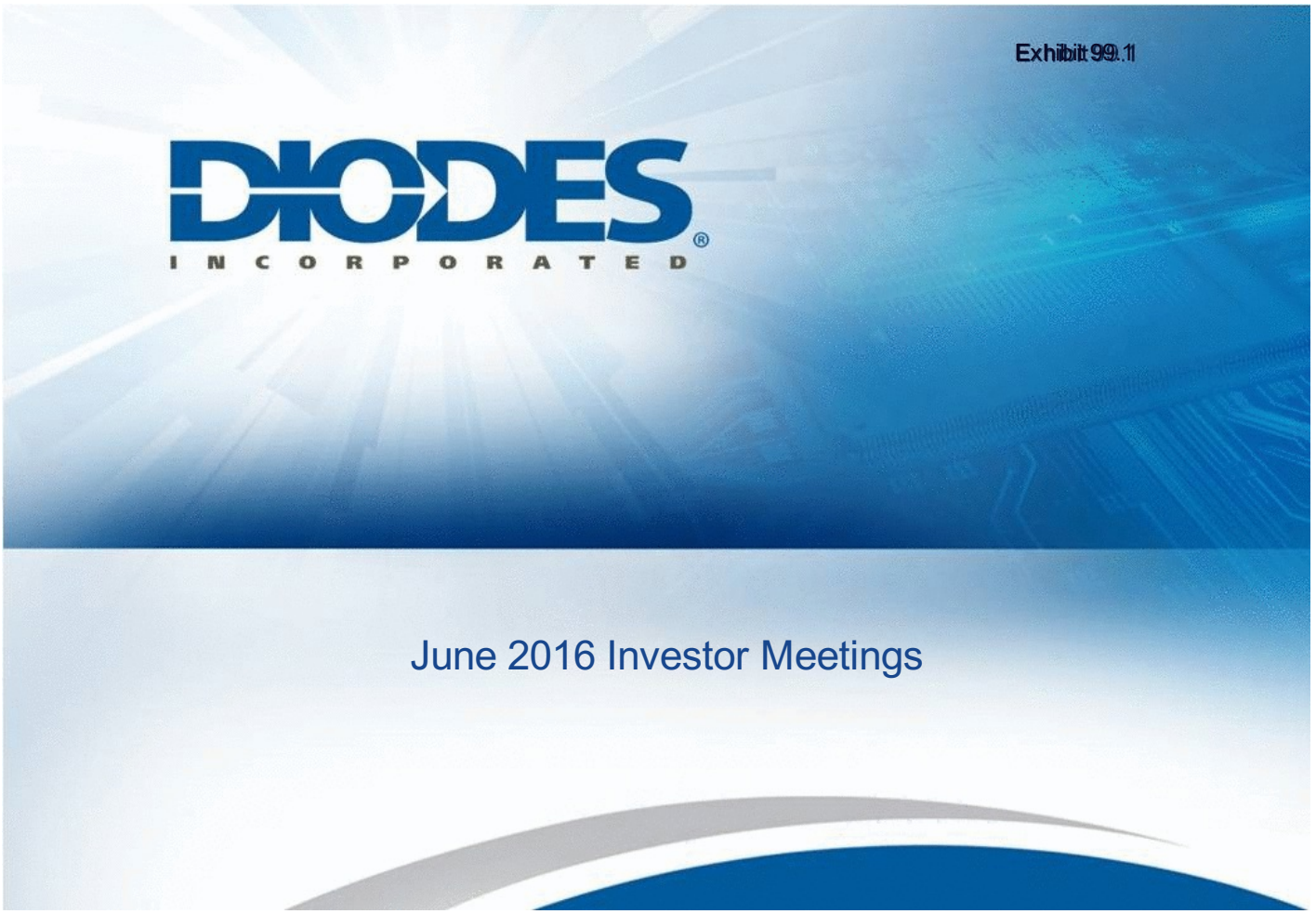
DIODES INCORPORATED

By /s/ Richard D. White
RICHARD D. WHITE
Chief Financial Officer

Index to Exhibits

Exhibit Number	Description
99.1	Corporate Presentation Slides

Exhibit 99.1



June 2016 Investor Meetings

Safe Harbor Statement

Any statements set forth herein that are not historical facts are forward-looking statements that involve risks and uncertainties that could cause actual results to differ materially from those in the forward-looking statements. Such forward-looking statements include, but are not limited to, statements regarding update to Diodes Incorporated's second quarter 2016 business outlook as of February 16, 2016, which includes the following: expect revenue to range between $230 million and $240 million, or up 3.3 to 7.7 percent sequentially; expect GAAP and non-GAAP gross margin to be 31.5 percent, plus or minus 2 percent; non-GAAP operating expenses are expected to be approximately 25 percent of revenue, plus or minus 1 percent; expect interest expense to be approximately 2.5 million; expect income tax rate to be 28 percent, plus or minus 3 percent, and shares used to calculate diluted EPS for the second quarter are anticipated to be approximately 49.5 million; purchase accounting adjustments related to Pericom and previous acquisitions of $4.4 million after tax are not included in these non-GAAP estimates; and other statements identified by words such as "estimates," "expects," "projects," "plans," "will" and similar expressions.

Potential risks and uncertainties include, but are not limited to, such factors as: the risk that such expectations may not be met: the risk that the expected benefits of acquisitions may not be realized; Diodes' business and growth strategy; the introduction and market reception to new product announcements; fluctuations in product demand and supply; prospects for the global economy; continued introduction of new products; Diodes' ability to maintain customer and vendor relationships; technological advancements; impact of competitive products and pricing; growth in targeted markets; successful integration of acquired companies and/or assets; Diodes' ability to successfully make additional acquisitions; risks of domestic and foreign operations, including excessive operation costs, labor shortages, higher tax rates and joint venture prospects; unfavorable currency exchange rates; availability of tax credits; Diodes' ability to maintain its current growth strategy or continue to maintain its current performance and loadings in manufacturing facilities; our future guidance may be incorrect; the global economic weakness may be more severe or last longer than Diodes currently anticipate; breaches of our information technology systems; and other information, including the "Risk Factors," detailed from time to time in filings with the United States Securities and Exchange Commission.

This presentation also contains non-GAAP measures. See the Company's press release on May 5, 2016 titled, "Diodes Incorporated Reports First Quarter 2016 Financial Results" for detailed information related to the Company's non-GAAP measures and a reconciliation of GAAP net income to non-GAAP net income.

DIODES INCORPORATED

Management Representative

Dr. Keh-Shew Lu

President and CEO

Diodes Incorporated	Since 2005
Texas Instruments	27 years

Experience:

- Senior Vice President of TI Worldwide Analog and Logic
- President of Texas Instruments – Asia

Education:

- Master's Degree and Doctorate in Electrical Engineering
  Texas Tech University
- Bachelor's Degree in Engineering
  National Cheng Kung University - Taiwan

Company Representative

Laura Mehrl

Director of Investor Relations

Since May 2010

Experience:

- Director of Investor Relations, Diodes Incorporated, Plano, Texas
- Senior Business Development Manager, STMicroelectronics, Carrollton, Texas
- Sales Director for Analog Devices Inc., Shanghai, China
- Product Marketing Manager at Texas Instruments (TI), Dallas, Texas
- Senior Engineer at Lattice Semiconductor Inc., Hillsboro, Oregon
- Wafer fab design engineer and product engineer at TI, Lubbock, Texas

Education:

- MBA with concentration in International Marketing, Texas Tech University
- BS in Electrical and Computer Engineering, University of Iowa

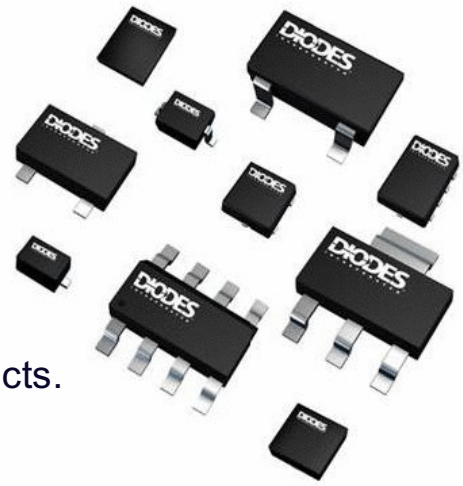
About Diodes Incorporated

A leading global manufacturer and supplier of high-quality **application specific, standard products** within the broad discrete, logic and analog markets, serving the **consumer, computing, communications, Industrial** and **automotive** segments.

DIODES INCORPORATED

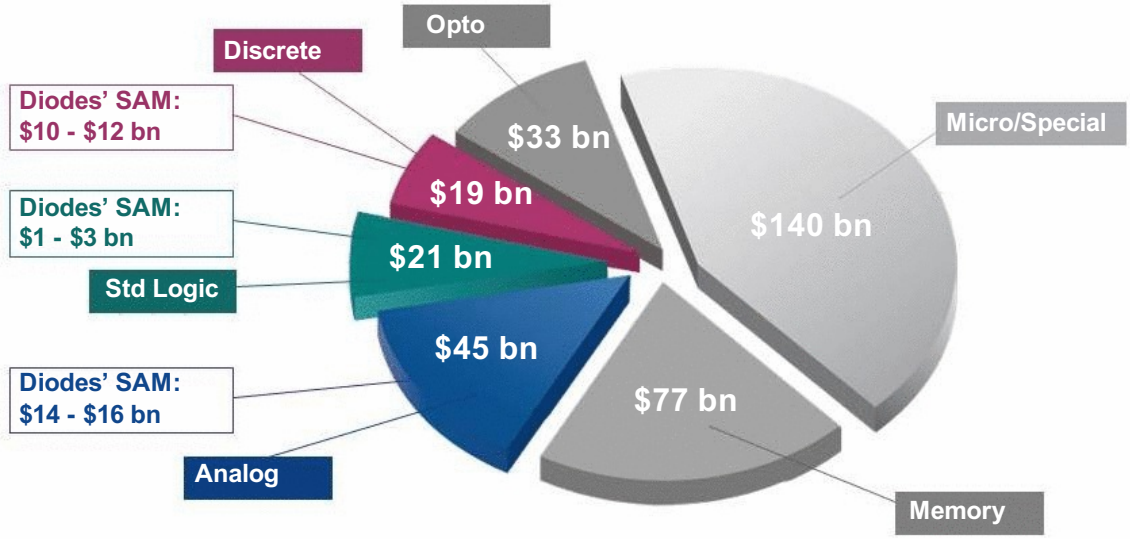
Business Objective

To consistently achieve above-market **profitable growth**, utilizing our innovative and cost-effective **packaging** and **silicon** technology, suited for **high volume, high growth** markets by leveraging process expertise and design excellence to deliver high quality semiconductor products.



Significant Market Opportunity

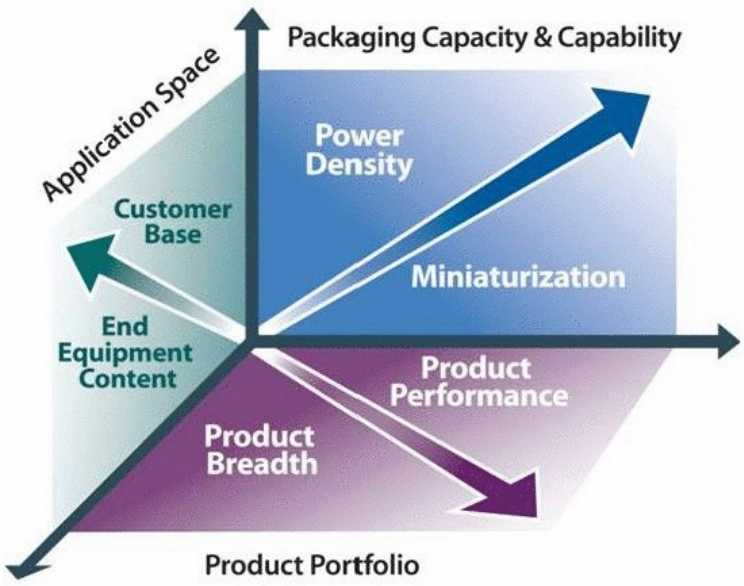
2015 Total Semiconductor Market ($335 bn)



Diodes Growth Strategy

Many Paths for Growth:

- **Product Portfolio**
  - Product arena
  - Product line expansion
  - Performance enhancement
- **Application Space**
  - Targeted end equipment
  - Broad customer base
  - Increased product coverage
- **Packaging Breadth**
  - Broad packaging portfolio
  - Increased power density
  - Small form factor



Pericom Fits Diodes' M&A Strategy

SYNERGISTIC FACTORS	Degree of FIT
Accretive in 1 year	1
Enter new product area	1
Access to new markets / new customers	1
Strengthen regional sales potential	1
Gain access to process and/or packaging technology	2
Synergistic with Diodes' packaging capabilities and capacity	2

1=Very synergistic, 2=Synergistic, 3=Fairly Synergistic

DIODES INCORPORATED

A Winning Combination

A Strong Global Partnership

DIODES INCORPORATED

2014 Revenue	$891M
2014 Gross Margin	31.1%

- High volume Discrete, Analog and Logic products
- Cost efficient manufacturing capabilities
- Strong global presence
- Broad product and customer base
- 3 C's and industrial with emerging focus on Automotive

+

PERICOM

2014 Revenue	$130M
2014 Gross Margin	42.3%

- Switches, Signal Integrity, Connectivity and Timing products
- Focus on emerging connectivity platforms
- Deep customer relationships
- Strong presence in networking and data center with growing automotive position

=

SYNERGIES

- Broader Analog and added mixed-signal product lines
- Expanded platform content in applications where Diodes is already strong
- Operating Synergies
- Technology presence to advance Diodes product roadmap
- Customer / application space depth within target markets

DIODES INCORPORATED

Broad Consolidated Product Offering

Discrete

Diodes
- Schottky Diodes
- Zener Diodes
- Switching Diodes
- SBR[a] Diodes
- Power Zener Diodes
- Power Rectifier Diodes

Rectifiers
- Schottky Rectifiers
- Super Barrier Rectifiers
- Standard Rectifiers
- Fast Recovery Rectifiers
- Bridge Rectifiers

MOSFETs
- Small Signal MOSFETs
- Power MOSFETs
- Protected MOSFETs
- High Voltage MOSFETS
- Complementary Pairs
- H-Bridges
- IntelliFET[a]

Protection Devices
- TVS
- Low CJ TVS
- Thyristor Surge Protection
- Data Line Protection

Bipolar Transistors
- Small Signal BJT
- Pre-biased BJT
- Medium Power BJT
- High Power BJT
- Darlington Transistors
- Gate-Drivers
- Low Saturation BJT
- H-Bridges

Function Specific Arrays
- Relay Drivers
- Discrete Load Switches
- Discrete Voltage Regulators
- MOSFET Gate-Drivers

Standard Products

Standard Linear

Linear Voltage Regulators
- Standard Linear Regulators
- Quasi Low Dropout Regulators
- Low Dropout Regulators

Voltage References
- Shunt References
- Micropower References

Current Monitors
- Current Output
- Voltage Output

Operational Amplifiers

Comparators

Timing Products
- Clocks
- Timer ICs
- Crystals
- Oscillators

Standard Logic ICs
- Single Gate
- Dual Gate
- Standard Logic
- Translaters
- Analog Switches
- Registers

ASSP

Power Management ICs

DC-DC Switching Regulators
- Buck
- Boost
- Buck/Boost/Inverter

AC/DC Solutions
- Primary-Side Regulators
- PWM
- BJT Switches
- Voltage

Power Switches
- Load Switches
- HDMI Switches

USB
- USB Switches
- Charging control

LED Drivers
- Charge Pump
- Boost
- Buck
- Linear LED Drivers
- LED backlighting

Power Supply
- MOSFET Controllers
- Active OR-ing Controllers
- Chargers

Connectivity

Switches
- Signal Switches
- Mux controllers

Signal Integrity
- Repeaters
- ReDrivers

Connectivity
- PCIe Bridges
- PCIe Packet Switches
- UARTs

Sensors
- Hall Switches
- Hall Latches
- Smart Fan Drivers
- Motor Controllers
- Temperature Sensors
- Magnetic Sensors

Digital Broadcast by Satellite
- Fixed Bias Generators
- Switched Bias Generators
- Multiplex Controllers
- Integrated Switch Matrix
- DBS Interface
- STB Power

Audio
- Class D Amplifiers
- Analog Input Amplifiers

DIODES INCORPORATED

Pericom Total Timing Solutions

Comprehensive portfolio for complete clock tree solutions

- Highest frequency clock buffers
- Low voltage, low power clock generators
- Real time clock (RTC) generators
- Programmable crystal oscillators
- Ultra low jitter crystal oscillators
- Temperature compensated crystal oscillators

Timing solutions for attractive markets

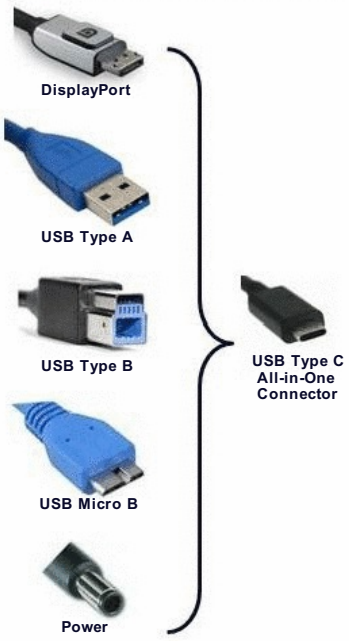
- Cloud computing / server storage
- Embedded automotive infotainment
- Internet of Things (IoT)

Owned manufacturing for advantaged cost infrastructure

- Integrated operations for crystal and crystal oscillator manufacturing
- Automated and automotive-certified facility in Taiwan focuses on crystal oscillators
- Fully automated facility in Jinan, China focuses on crystal manufacturing

DIODES INCORPORATED

USB Type C Connector



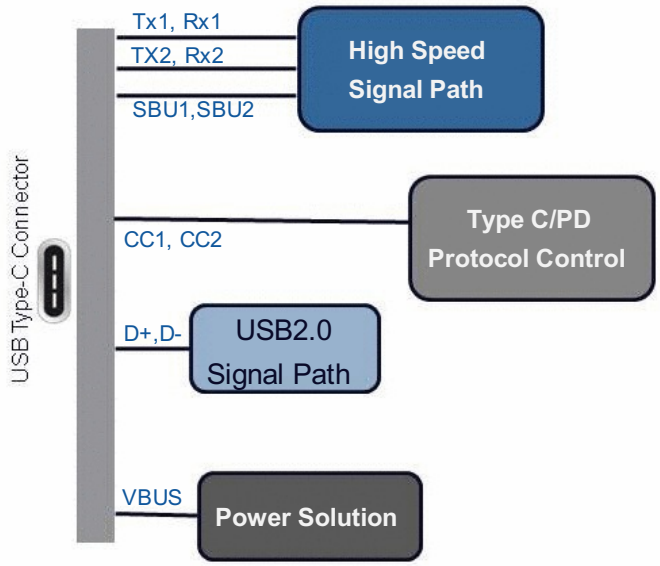
Highly Attractive Market Opportunity

- 10Gbps reversible connector: single USB cable for data, audio, video and power
- Driven by next generation mobility platforms: notebook, smart phone, tablet, portable consumer
- Flexible “charge anywhere” approach to personal electronics
- Will drive conversion in storage, server, and Ultra HD displays

Combined Diodes+Pericomoffers complete system solution

- Extensive Pericom offering for USB connectivity:
  - High performance cross bar signal switches
  - USB3 / DisplayPort1.2 ReDrivers
  - USB charging controllers
  - High bandwidth USB3.1 multiplex/demultiplex
  - Plug orientation detectors
- Diodes USB portfolio focused on power management:
  - USB power switches
  - Transient voltage suppressors
  - ACDC primary side controllers
  - Power MOSFETs
  - Active rectifier

USB Type C Power Delivery



High-Speed Serial Connectivity

- USB3.0/3.1 and DP/HDMI MUX
- USB3 Crossbar
- USB3.0/3.1 Re-Driver
- Type C host CC Detection
- Type C Protocol Controller
- USB2.0 Mux
- Audio Switch

Analog & Power

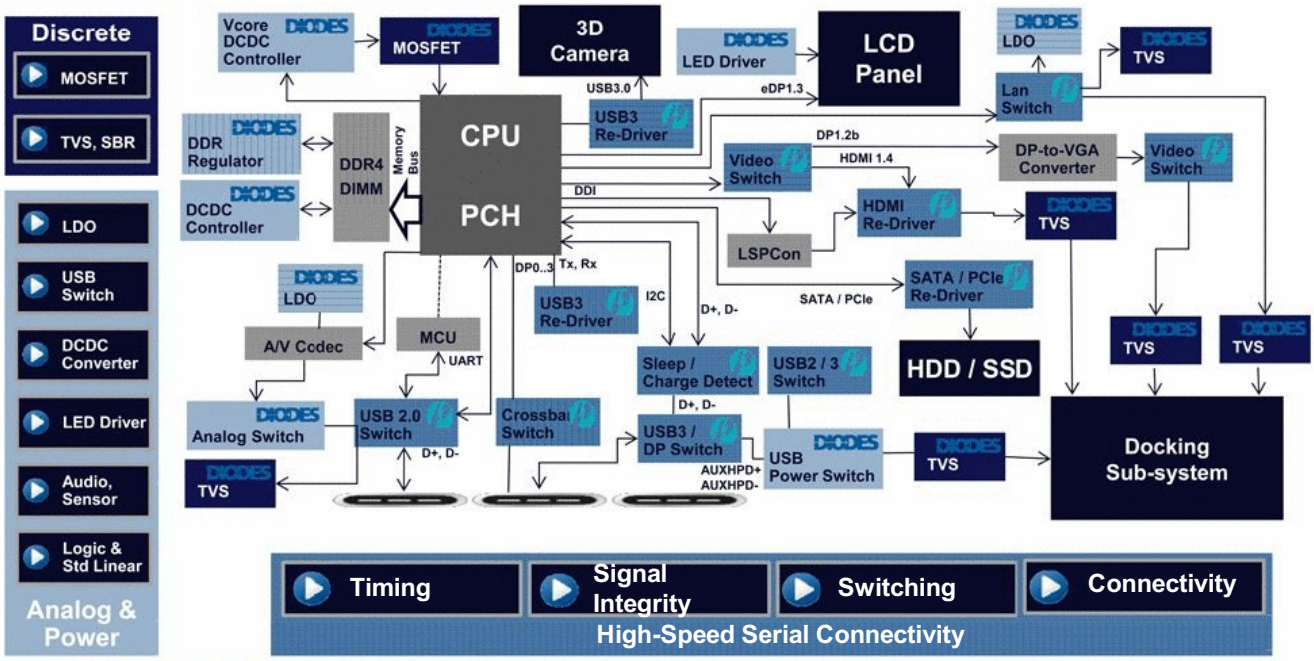
- Type C Charger CC Detection
- PD Adaptor Controller
- High Voltage LDO
- High Voltage USB Power Switch
- DCDC Converter
- ACDC Power Solutions

Discrete

- TVS for USB3.0/3.1
- High Voltage Power Switch
- Load Switch
- MOSFET

DIODES INCORPORATED

Complete Platform Solutions: Notebooks



Performance Enhancement

SKY Rectifiers	**SBR® (Super Barrier Rectifiers)** (Vb < 400v)	**DIODESTAR™ Rectifiers** (Vb > 600v)
MOSFETs	**DIOFET™** (Low $R_{DS(on)}$, Vb < 100V)	**DIODESTAR™ MOSFETs** (Ultra low $R_{DS(on)}$, Vb > 600V)
Bipolar LDO	**CMOS LDO** (Low power)	**Low Noise LDO**
DC-DC (Asynchronous)	**DC-DC** (Asynchronous, high current)	**DC-DC** (Synchronous, with low & high current)
AC-DC (Secondary side controllers)	**AC-DC** (Primary side controllers, Secondary side controllers)	**AC-DC** (Quick Charging Controller solutions)
LED Drivers (DC Input)	**LED Drivers** (AC Input)	**LED Drivers** (Full-Voltage Range, Triac-Dimmable/Non-Dimmable)

Diodes' product upgrade has expanded our SAM.

DIODES INCORPORATED

Efficiency, Functionality and Control for Smartphones

- **LED Backlighting**
  - LED Drivers
  - Boost Converters
  - Schottky Diodes
- **LED Flash Module**
  - Camera Flash Drivers
  - ZXMN series MOSFETs
- **LCD / OLED Display Bias**
  - LCD Bias ICs
  - OLED Bias ICs
  - Schottky Diodes
- **Battery Power Management**
  - USB Power Switches
  - Current Monitors
  - Charger ICs
  - Low-Saturation Bipolar Transistors
  - ZXMP series MOSFETs

- **GPS Antenna Detection**
  - Current Monitors
- **RF Power Amplifier**
  - Low Dropout Regulators
- **System Voltage Conversion**
  - Low Dropout Regulators
  - DC-DC Converters
  - Schottky Diodes
  - Low-Saturation Bipolar Transistors
- **System Interface**
  - USB Power Switches
  - Zener and TVS Arrays
- **Keypad Backlighting**
  - LED Drivers
  - Boost Converters
  - Schottky Diodes
- **Audio Amplifier**
  - Class D Amplifier

DIODES INCORPORATED

Strong Relationships Drive LCD/LED TV Product Roadmaps

- **LCD Display Buffer**
  40V High-gain BJT
- **System Power Conversion**
  Low Dropout Regulators
  DC-DC Converters
  Voltage References
  Synchronous MOSFET Controllers
  40V/100V SBR and Schottkys
  Bridge Rectifier Diodes
- **LCD LED Backlighting**
  Current Monitors
  400V High-gain NPN BJT
  60V/100V High-gain NPN BJT
  60V/100V N-channel MOSFETS
- **CCFL Backlighting**
  30V Low On-resistance MOSFETs

- **Antenna Tuner**
  DC-DC Converters
  40V Schottkys
- **System Interface**
  USB Power Switches
  Zener and TVS Arrays
- **System Power Management**
  Buck DC-DC Converters
  Low Dropout Regulators
  20V/30V/40V SBR® and Schottkys
  30V P-Channel MOSFETs
  30V Low-saturation PNP BJT
- **Audio Amplifier**
  Buck DC-DC Converters
  Schottky Diodes
  SBR
  Class D Amplifier

DIODES INCORPORATED

Product Breadth and Performance for Computing Platforms

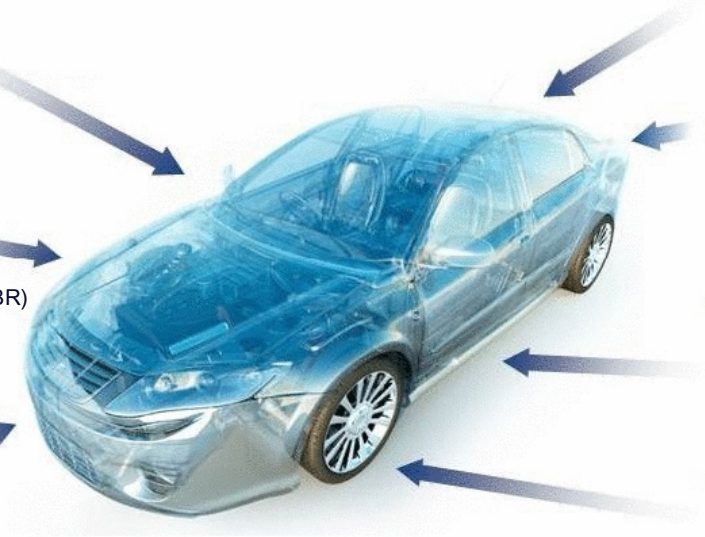
- **LCD / LED Backlighting**
  - LED Drivers
  - Boost Converters
  - Schottky Diodes
- **System Voltage Conversion**
  - Low Dropout Regulators
  - DC-DC Converters
  - Schottky Diodes
  - Low-Saturation BJT
- **Battery Power Management**
  - Current Monitors
  - Load Switches
  - Low-Saturation BJT
  - ZXMP series MOSFETs
- **Open / Close Detection**
  - Hall Effect Sensors
  - Hall Effect Drivers

- **Audio Amplifier**
  - Buck DC-DC Converters
  - Schottky Diodes
  - Super Barrier Rectifiers
  - Class D Amplifier
- **Wireless Connectivity**
  - DC-DC Converters
  - Low Dropout Regulators
- **System Power Management**
  - Buck DC-DC Converters
  - Low Dropout Regulators
  - Super Barrier Rectifiers
  - Schottky Diodes
  - P-Channel MOSFETs
  - Low-Saturation BJT
- **System Interface**
  - USB Power Switches
  - Zener and TVS Arrays

DIODES INCORPORATED

Automotive Quality for Demanding Automotive Applications

- **Body Control Module**
  Bipolar Transistors
  Shunt Regulator
  Voltage Reference
  IntelliFET
  MOSFETs
  Hall Sensor
- **Powertrain**
  MOSFET
  Hall Sensor
  Super Barrier Rectifier® (SBR)
- **Daytime Running Lights**
  LED Drivers
  Schottky Diodes
  MOSFETs
  Bipolar Transistors



- **Automotive Networking**
  ESD Protection
  TVS Protection
- **Interior Light**
  LED Drivers
  Schottky Diodes
  MOSFETs
  Bipolar Transistors
- **Seat Control Module**
  Hall Sensor
  SBR
  IntelliFET®
  Voltage Reference
- **Braking Control Unit**
  Voltage Reference
  IntelliFETs
  MOSFETs
  Hall Sensor

DIODES INCORPORATED

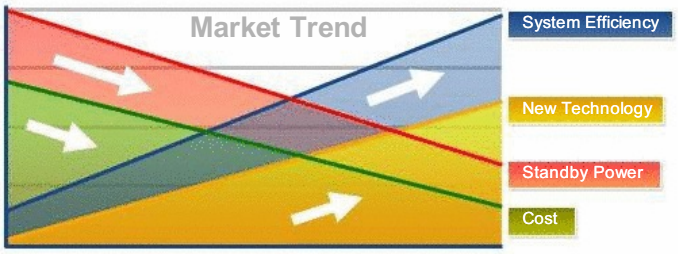
Power and Signal Management for the Broad Industrial Market

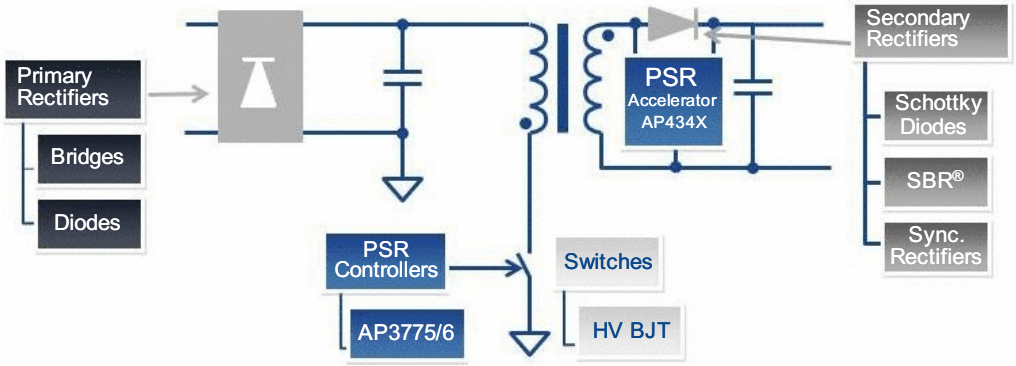
- **Illumination**
  - LED Drivers
  - Synchronous Rectifiers
  - HV Rectifiers and Bridges
  - SBRs
  - HV Switches
  - MOSFETs
- **System Protection**
  - Hall Sensors
  - ESD Protection
  - TVS Protection
- **Signal Conditioning**
  - Op Amps
  - Comparators
  - Linear Hall
  - Voltage Reference
  - Logic
  - Current Monitors
  - ESD Protection
  - TVS Protection

- **Actuators/Drivers**
  - Hall Sensors
  - Relay Drivers
  - IntelliFET
  - MOSFETs
- **Motor Control**
  - Hall Sensors
  - Motor Control/Drivers
  - MOSFETs
  - H-Bridges
  - SBR
  - Gate Drivers
- **Power Management**
  - AC-DC Converters
  - DC-DC Converters
  - LDO Regulators
  - HV Regulators
  - Shunt Regulators
  - Gate Drivers
  - Synchronous Rectifiers
  - HV Rectifiers and Bridges
  - SBRs
  - HV Switches

DIODES INCORPORATED

Complete Charger and Power Adapter Solution and Trend



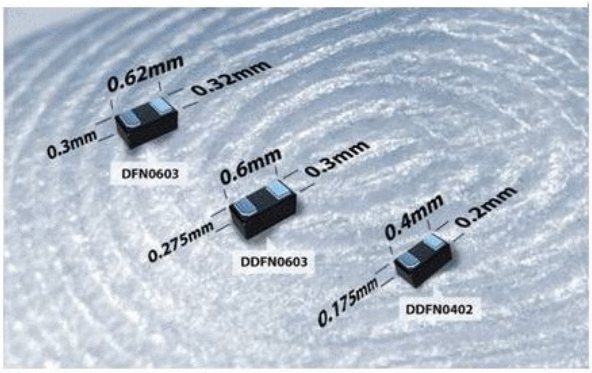


Packaging Focus: Miniaturization and Power Efficiency

Packaging Focus: Miniaturization and Power Efficiency

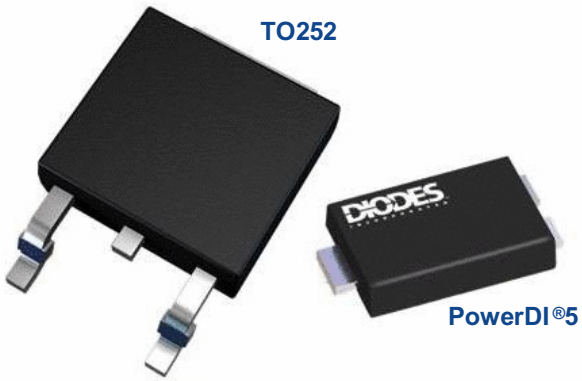
Miniaturization

DDFN0402 Possibly the smallest Discrete semiconductor package.



Power Efficiency

Compared to a TO252, the PowerDI®5 package delivers twice the power density from a 55% smaller footprint.



Efficient Manufacturing + Superior Processes

Packaging

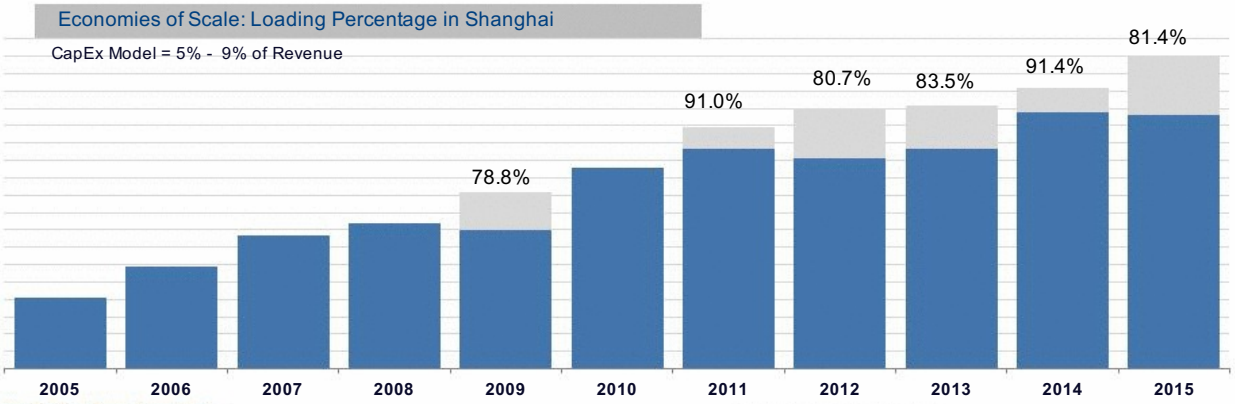
- Shanghai-based packaging with capacity approximately 30 billion units
- The new packaging facility in Chengdu has a potential capacity of 5X that of Shanghai
- Additional packaging facilities in Neuhaus, Germany and in Chengdu, China

Wafer Fabs

- Two discrete fabs, two analog fabs in Kansas City, Missouri (5" and 6"), Oldham, United Kingdom (6"), and Shanghai (6") respectively
- Bipolar, BiCMOS, CMOS & BCD process
- Strong engineering capabilities

Economies of Scale: Loading Percentage in Shanghai

CapEx Model = 5% - 9% of Revenue



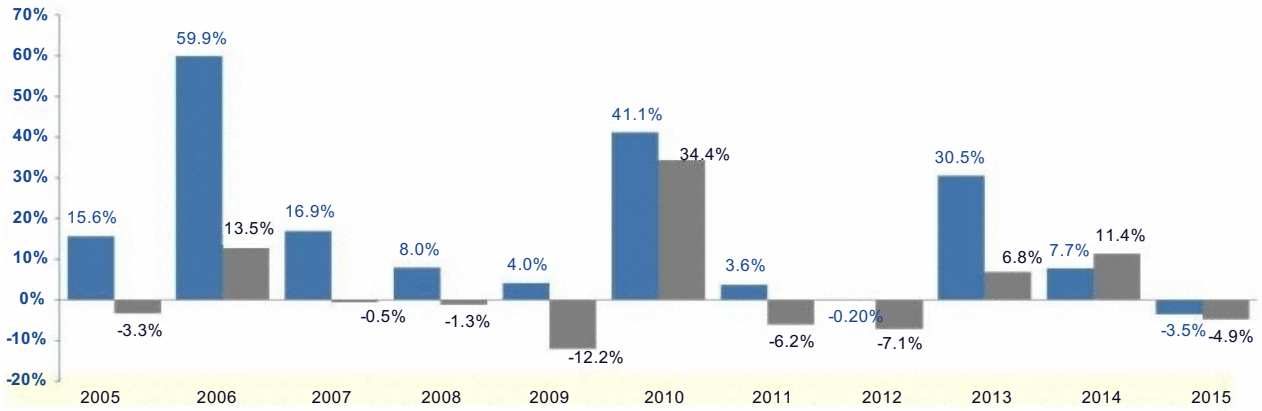
Collaborative Customer Relationships

DIODES INCORPORATED

Outperforming the Industry

Annual Revenue Growth Rates

2005 to 2015 Growth
Diodes Inc.: 14.7%
SAM Industry: 3.1%



DIODES Industry (Discrete + Analog + Logic)

DIODES INCORPORATED

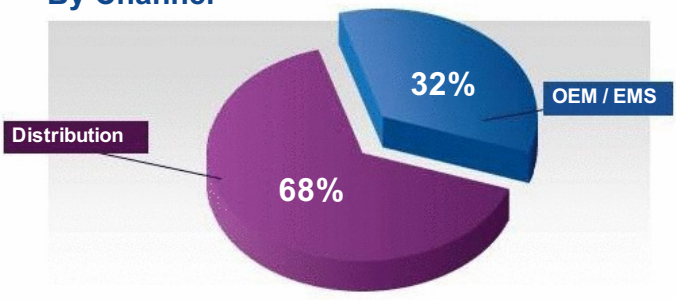
Revenue Growth

(In millions)

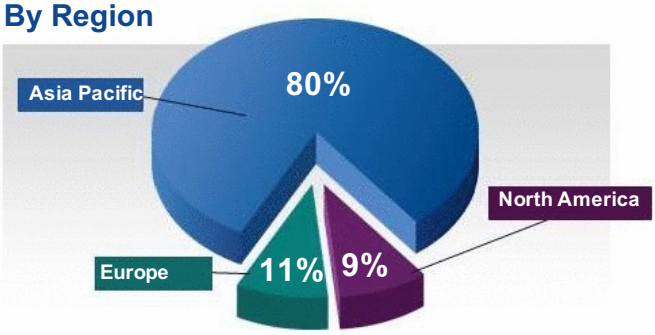
* (Acquisition Years)

Revenue Profile – 1Q2016

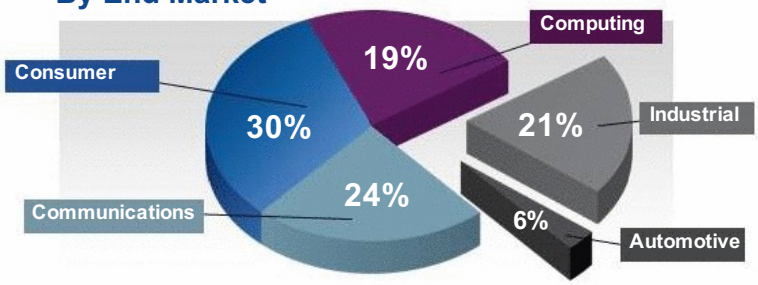
By Channel



By Region



By End Market



DIODES INCORPORATED

First Quarter 2016 Financial Performance

In millions, except per share	1Q15	4Q15	1Q16
Revenue	$206.2	$214.4	$222.7
Revenue Growth	8.0%	3.9%	
Gross Profit (GAAP)	$63.9	$53.6	$64.2
Gross Profit Margin % (GAAP)	31.0%	25.0%	28.8%
Net Income (GAAP)	$11.1	-$4.8	-$1.7
Net Income (non-GAAP)	$12.7	$6.7	$5.9
EPS (non-GAAP)	$0.26	$0.14	$0.12
Cash Flow from Operations	$38.6	$19.7	$25.5
EBITDA (non-GAAP)	$35.3	$16.6	$24.9

Balance Sheet

In millions	Dec 31, 2014	Dec 31, 2015	Mar 31, 2016
Cash	$243	$218	$237
Short-term Investments	$12	$65	$43
Inventory	$182	$203	$205
Current Assets	$676	$751	$745
Total Assets	$1179	$1599	$1580
Long-term Debt	$141	$454	$440
Total Liabilities	$369	$756	$734
Total Equity	$810	$843	$846

2Q 2016 Business Outlook

- Expect revenue to range between $230 million and $240 million, or up 3.3 to 7.7 percent sequentially;
- Expect GAAP and non-GAAP gross margin to be 31.5 percent, plus or minus 2 percent;
- Non-GAAP operating expenses are expected to be approximately 25 percent of revenue, plus or minus 1 percent;
- Expect interest expense to be approximately 2.5 million;
- Expect income tax rate to be 28 percent, plus or minus 3 percent, and shares used to calculate diluted EPS for the second quarter are anticipated to be approximately 49.5 million;
- Purchase accounting adjustments related to Pericom and previous acquisitions of $4.4 million after tax are not included in these non-GAAP estimates.

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Thank you

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